

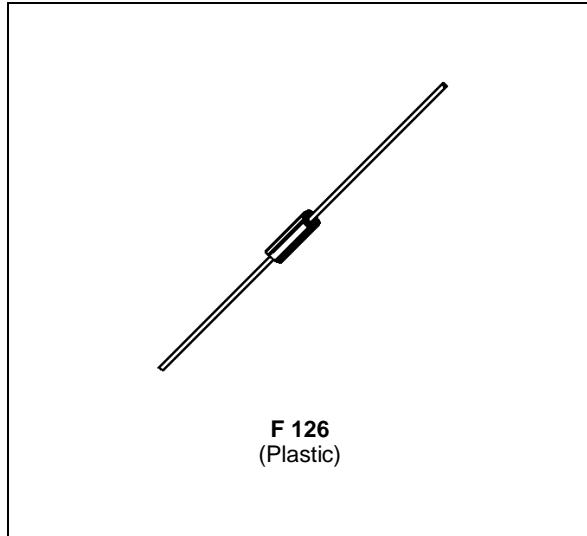


**SGS-THOMSON**  
MICROELECTRONICS

**PLQ 08**  
**PLQ 1**

## FAST RECOVERY RECTIFIER DIODES

- VERY FAST FORWARD AND REVERSE RECOVERY DIODES



### SUITABLE APPLICATION

- SWITCHING POWER TRANSISTORS DRIVER CIRCUITS (SERIES DIODES IN ANTISATURATION CLAMP SPEED UP DIODE IN DISCRETE DARLINGTON...)
- THYRISTORS GATE DRIVER CIRCUITS
- HIGH FREQUENCY RECTIFICATION

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
$I_{F\text{RM}}$	Repetitive Peak Forward Current	20	A
$I_F(\text{AV})$	Average Forward Current*	1	A
$I_{F\text{SM}}$	Surge non Repetitive Forward Current	20	A
$P_{\text{tot}}$	Power Dissipation*	1.7	W
$T_{\text{stg}} - T_j$	Storage and Junction Temperature Range	- 40 to 125	°C
$T_L$	Maximum Lead Temperature for Soldering during 10s at 4mm from Case	230	°C

Symbol	Parameter	PLQ 08	PLQ 1	Unit
$V_{\text{RRM}}$	Repetitive Peak Reverse Voltage	80	100	V
$V_{\text{RSM}}$	Non Repetitive Peak Reverse Voltage	80	100	V

### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{\text{th}}(j-a)$	Junction-ambient*	60	°C/W

\* On infinite heatsink with 10mm lead length.

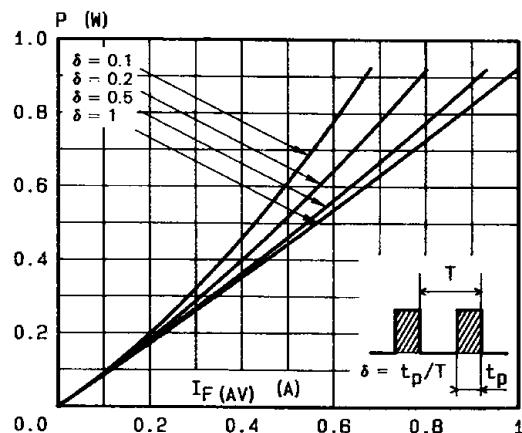
**ELECTRICAL CHARACTERISTICS****STATIC CHARACTERISTICS**

<b>Symbol</b>	<b>Test Conditions</b>		<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
$I_R$	$T_j = 25^\circ C$	$V_R = V_{RRM}$			10	$\mu A$
	$T_j = 100^\circ C$				0.5	mA
$V_F$	$T_j = 25^\circ C \quad I_F = 1A$				1.1	V

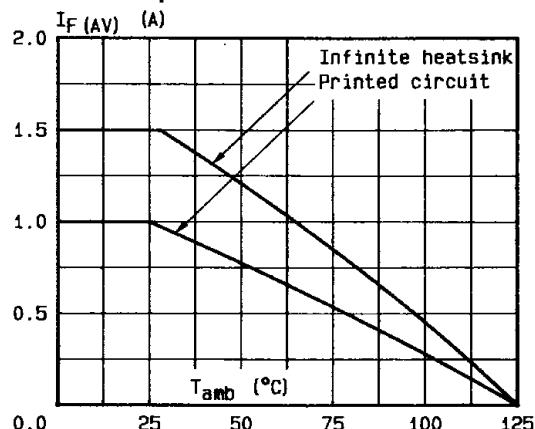
**RECOVERY CHARACTERISTICS**

<b>Symbol</b>	<b>Test Conditions</b>			<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Unit</b>
$t_{rr}$	$T_j = 25^\circ C$	$I_F = 1A$	$di_F/dt = -50A/\mu s$			50	ns
$t_{fr}$	$T_j = 25^\circ C$ Measured at $1.1 \times V_F$	$I_F = 1A$	$t_r = 20ns$			50	ns

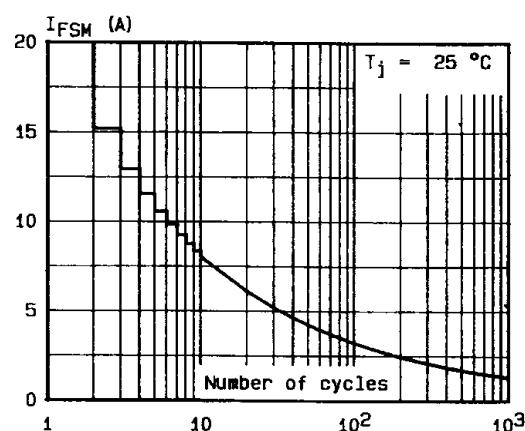
**Figure 1. Power losses versus average current.**



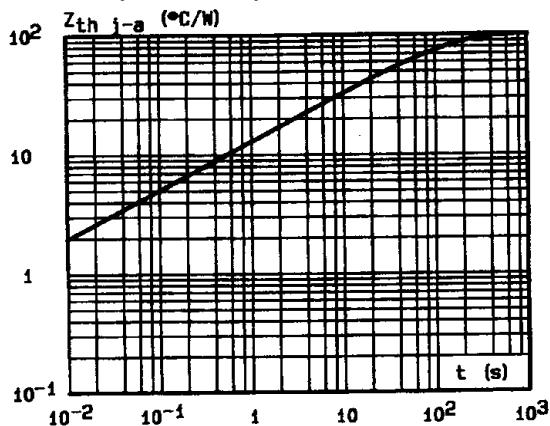
**Figure 2. Allowable DC current versus ambient temperature.**



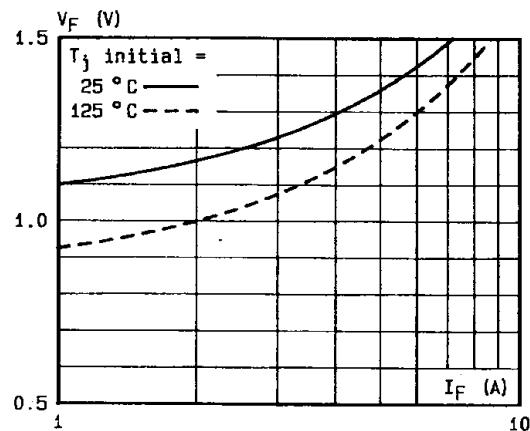
**Figure 3. Non repetitive surge peak current versus number of cycles.**



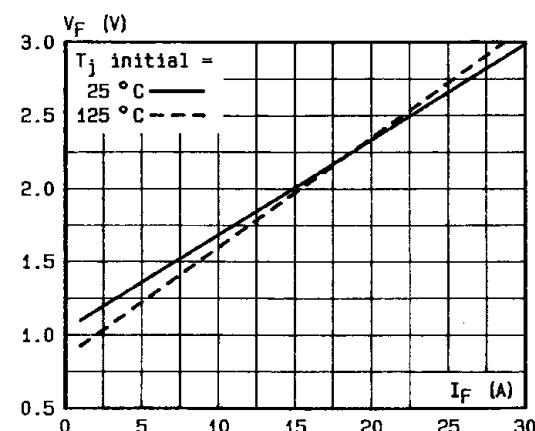
**Figure 4. Transient thermal impedance junction-ambient. Printed circuit versus pulse duration (L = 10 mm).**



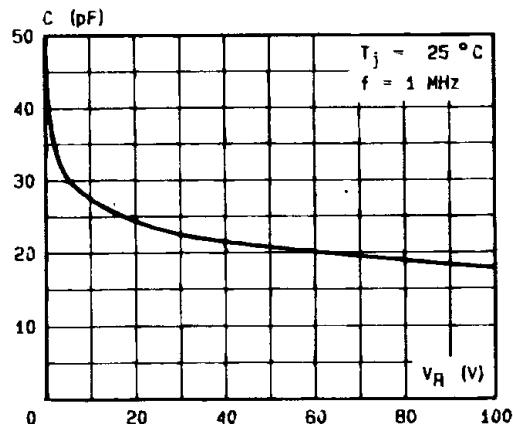
**Figure 5. Voltage drop versus forward current.**



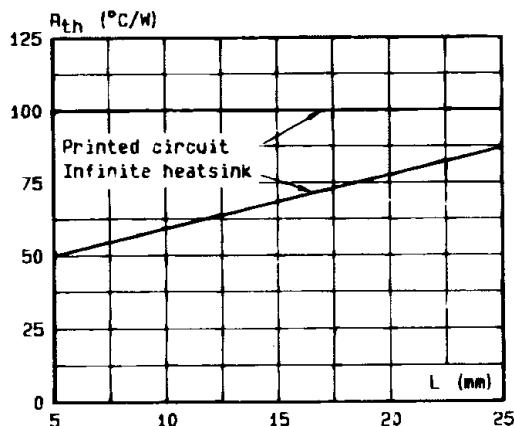
**Figure 6. Voltage drop versus forward current.**



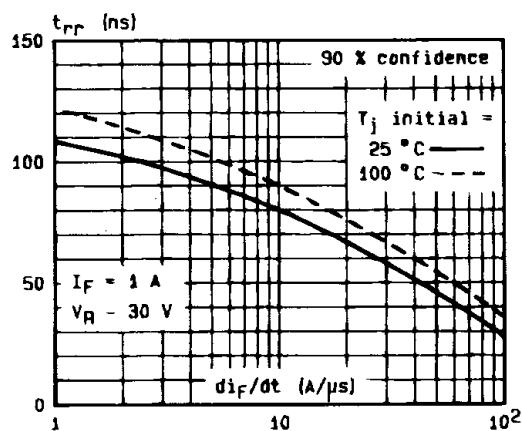
**Figure 7. Capacitance versus reverse voltage applied.**



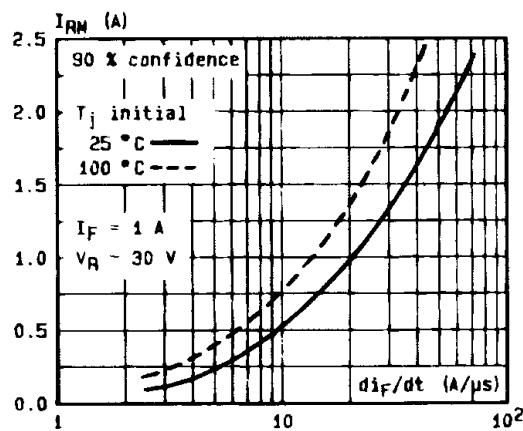
**Figure 8. Thermal resistance junction-ambient versus lead length.**



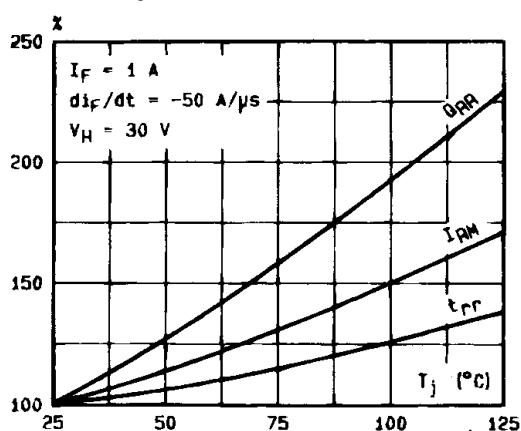
**Figure 9. Recovery time versus  $\text{di}_F/\text{dt}$ .**



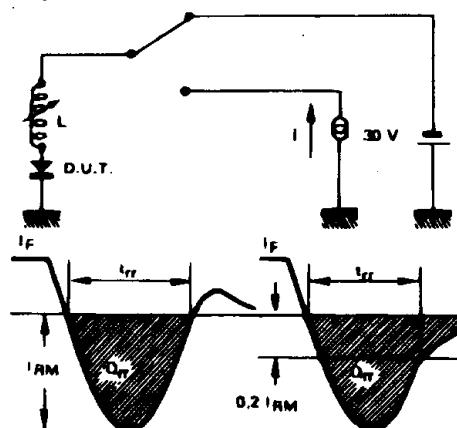
**Figure 10. Peak reverse current versus  $\text{di}_F/\text{dt}$ .**



**Figure 11. Dynamic parameters versus junction temperature.**

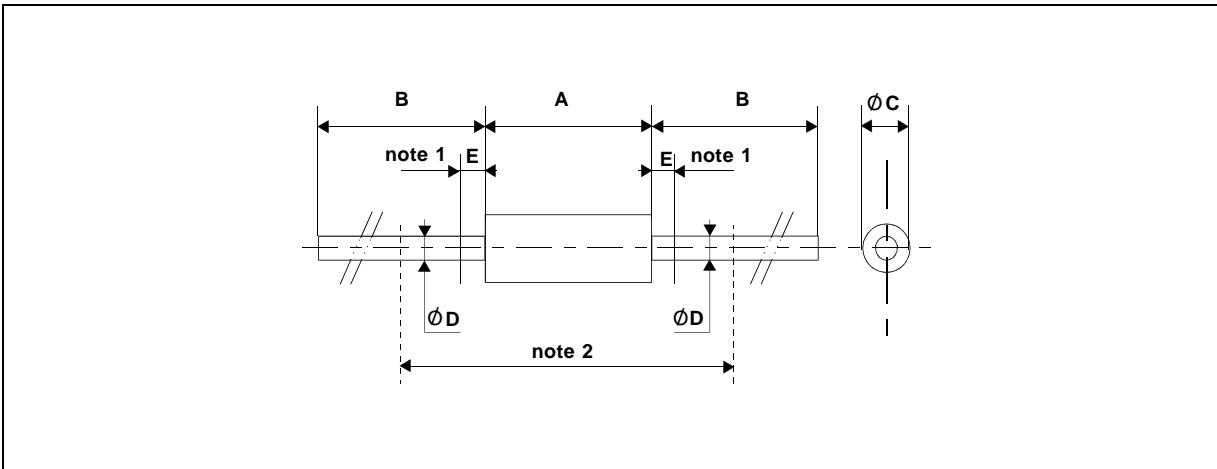


**Figure 12. Measurement of  $t_{rr}$  (fig. 8) and  $I_{RM}$  (fig. 10).**



## PACKAGE MECHANICAL DATA

F 126 (Plastic)



REF.	DIMENSIONS				NOTES	
	Millimeters		Inches			
	Min.	Max.	Min.	Max.		
A	6.05	6.35	0.238	0.250	1 - The lead diameter Ø D is not controlled over zone E	
B	26		1.024		2 - The minimum axial length within which the device may be placed with its leads bent at right angles is 0.59" (15 mm)	
Ø C	2.95	3.05	0.116	0.120		
Ø D	0.76	0.86	0.029	0.034		
E		1.27		0.050		

Cooling method: by convection (method A)

Marking: type number

Weight: 0.4g

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